Controlled placement of highly aligned carbon nanotubes for the manufacture of arrays of nanoscale torsional actuators

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Abstract
We have fabricated ordered arrays of nanoscale torsional actuators consisting of metal mirrors bonded to precisely oriented multiwall carbon nanotubes. The fabrication is facilitated by a new nanotube positioning method which employs localized electron beam activation of polymer residue on a silicon oxide surface.

1. Introduction
Recent advances in nanoscale synthesis and fabrication techniques have opened the door to the manufacture of true nanoelectromechanical systems (NEMS). For example, multiwall carbon nanotubes (MWCNTs) have been utilized as key enabling elements for nanoscale electrostatically driven torsional [1] and rotational [2] actuators, orders of magnitude smaller than their microelectromechanical (MEMS) counterparts. Due to their small size, robust design and near-perfect atomic structure, such constructs hold great promise as building blocks for complex nanoelectromechanical systems. The utility of individual actuators can be significantly increased by their incorporation into arrays of devices. Such arrays could serve in a variety of applications, including adaptive optics, high frequency mechanical filters, mass sensors, and microfluidic gates and pumps.

A fundamental challenge in the development of NEMS arrays (and of nanotube- and nanowire-based devices in general) is the large-scale controlled placement of molecular sized building blocks on a substrate. Methods based on chemical vapour deposition (CVD) avoid this problem by, for example, growing nanotubes directly on the substrate where they ultimately will be located [3]. Unfortunately, such methods are unable to produce very high quality multi-walled carbon nanotubes as are often required for NEMS applications [2, 4, 5]. Furthermore, CVD is commonly a high temperature process, which severely limits compatibility with substrate materials or other system components. Hence there is much interest in low temperature techniques to aid in the selective placement and alignment of prefabricated nanostructures. There has been some progress in developing fluidic techniques for aligning nanowires [6] and nanotubes [7–9], and various functionalization schemes have been explored for placing nanotubes on particular areas of a substrate [10–12]. Unfortunately, most of these methods necessitate rather complex substrate topology or involved and limiting chemistry.

We have developed a combination of novel room-temperature methods for both aligning and selectively depositing nanotubes onto a topologically benign surface. Using these methods, which can easily be integrated into semiconductor manufacturing processes, we have fabricated arrays of aligned torsional NEMS devices based on MWCNTs.

2. Fabrication process
Figure 1 outlines the fabrication process. High quality MWCNTs are grown using the arc-plasma method and are dispersed in solution. A silicon/silicon oxide substrate is coated with electron beam resist, which is then soaked in acetone to leave only a very thin polymer layer. The substrate is then selectively exposed to an electron beam in situ in an FEI Sirion XL30 scanning electron microscope, which activates
Effective torsional spring constants range from $10^{-12}$ N m, depending on the MWCNT geometry. Typical devices have moments of inertia $\sim 10^{-30}$ kg m$^2$, yielding resonance frequencies in the tens of megahertz range (with smaller paddle sizes and shorter exposed MWCNT lengths the resonance frequencies can be extended to above 1 GHz). The key advance of the present work is the ability to produce such devices in an array configuration.

Actuators of the type shown in figure 2 have been previously individually fabricated and characterized [1, 2, 13]. Effective torsional spring constants range from $10^{-15}$ to $10^{-12}$ N m, depending on the MWCNT geometry. Typical devices have moments of inertia $\sim 10^{-30}$ kg m$^2$, yielding resonance frequencies in the tens of megahertz range (with smaller paddle sizes and shorter exposed MWCNT lengths the resonance frequencies can be extended to above 1 GHz). The key advance of the present work is the ability to produce such devices in an array configuration.

We describe in detail the key enabling step in the array fabrication process, namely MWCNT targeted deposition and alignment. Our alignment method exploits the surface velocity obtained by a fluid as it flows off of a spinning substrate, and is distinct from previous alignment attempts involving either dielectrophoresis [14] or deposition from a solution driven across a surface by gas [7, 8] or microfluidic flow [6]. We use arc-grown MWCNTs with typical diameters of 10–25 nm as measured by transmission electron microscopy (TEM). The MWCNTs are suspended in orthodichlorobenzene (ODCB) at a concentration of 100 mg l$^{-1}$ by ultrasonication in a VWR model 75D Aquasonic bath for 60 s at level 3. TEM observation shows that this level of ultrasonication is enough to separate most MWCNT bundles into individual MWCNTs. The suspension is then pipetted drop by drop onto the centre of a silicon substrate mounted on a spin coater rotating at 3000 rpm. The suspension flows radially across and off the substrate. Once the surface is dry, the next drop is deposited. We find that if the next drop is deposited while the substrate is still wet, the deposition is less dense and contains a larger percentage of unaligned nanotubes. Although the MWCNTs of figure 3 are aligned, they are still randomly positioned. For many multi-component engineered NEMS devices, including arrays, pre-determined positional order is necessary. The deposition process can be further refined by locally treating the substrate to place MWCNTs in target locations. Previous targeting attempts via dielectrophoresis have been made using self-assembled monolayers (SAMs) with polar functional groups [10–12]. The success of these techniques is dependent upon the quality of the SAM, however, with degraded performance occurring when more (or less) than a monolayer is deposited [15]. Ideally, localized nanotube deposition should involve a surface layer which is simple to deposit and insensitive to variations in thickness.

Our location targeting method exploits a surface layer that is already present in standard lithographic work and does
not require a single monolayer. The layer consists of the residual polymer left behind when resists used in electron beam lithography are removed by an acetone wash. In this work, the resist consisted of a copolymer of 8.5% methacrylic acid (MAA) in methyl methacrylate (MMA) formulated in ethyl lactate at 6% (available from MicroChem Corp.), and was spin-coated at 3000 rpm for 30 s onto a silicon substrate with 1\( \mu \)m of thermally grown oxide. It was then baked on a hot plate at 185\(^\circ\)C for 3 min and stripped in acetone for 5 min. When left untreated, the residual coating actually inhibits nanotube deposition out of ODCB, as evidenced by lower deposition rates than those seen on pristine silicon substrates.

Targeted adhesion of nanotubes by this layer is activated by exposure to the low energy electron beam of a scanning electron microscope (SEM). Figure 4(a) shows the edge of a patterned area onto which nanotubes have been randomly deposited with no alignment. The preferential deposition of nanotubes on the selected area (lower half of the figure) is easily apparent. By controlling the raster of the electron beam we are able to create any desired adhesion pattern on the substrate, with the untreated residual coating inhibiting deposition elsewhere. By combining targeted adhesion and fluidic alignment, deposition of nanotubes in an ordered fashion becomes feasible. Figure 4(b) shows single-walled carbon nanotubes (SWCNTs) which have been deposited from a solution flowing parallel to patterned lines of activated substrate, while figure 4(c) is an example of MWCNTs deposited from a solution flowing at \( \sim 70^\circ \) to patterned lines of activated substrate; here we observe that the trailing edge of the nanotubes adheres to the targeted region. If the activated regions are dots rather than lines, then a targeted array is possible, as is the case for the two-dimensional MWCNT array underlying the devices of figure 2. By changing the size and
Once arrays of MWCNTs or similar structures have been deposited, further processing and device fabrication can be relatively straightforward. In our torsional actuator demonstration array, the nanotubes are first placed in an array configuration on a degenerately doped silicon wafer with 1 µm of thermally grown oxide on its top surface. The paddle and anchors are then patterned by electron beam lithography and deposited by electron beam evaporation of gold. To suspend the devices, approximately 500 nm of the silicon oxide is selectively removed with a buffered hydrofluoric acid etch. In the prototype array shown in figure 2, each row of actuators is connected together to simplify the wiring arrangement and still allow for semi-independent actuation. The actuators could be made completely independent by using a more complicated wiring scheme, perhaps incorporating multiple conducting layers to avoid shorting the leads from one device to another. Multilayer processing would also allow for higher density packing of devices.

Torsional actuator arrays operating at radio frequencies might find use in optical switching or in adaptive optics applications. With each actuator serving as a high frequency mechanical filter, such an array could also be used for parallel signal processing in telecommunications. Furthermore, by tracking the frequency shift of each actuator, an array of individually functionalized actuators could be used as mass sensors for simultaneous environmental monitoring of a variety of substances.

4. Conclusions

In summary, we have fabricated arrays of torsional actuators using a novel nanotube positioning technique. The nanotubes are oriented by fluid flow across a spinning substrate and adhere preferentially to regions that have been activated by a focused electron beam. The adhesion is found to be due to extreme modification of a residual polymer layer already present in lithographic work. By varying the flow direction and electron beam exposure we are able to deposit nanotubes in a variety of patterns that can then be contacted by standard lithography.

Our ability to orient and preferentially place molecular structures paves the way for their integration into mass produced devices. Aside from the torsional actuator array already described, an immediate, simple application is the use of nanotubes as electrical interconnects between units of an integrated circuit (especially desirable due to their ability to carry extremely high electrical and thermal current densities). The unique physical properties of carbon nanotubes could be harnessed in other applications as well, such as high density arrays of field effect transistors, gas sensors or biosensors. Alternative geometrical configurations, including radially aligned nanotubes, crossed nanotubes etc, could be easily fabricated using the techniques described here.

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